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				Application Number	10/597,199-Conf. #7625
				Filing Date	July 14, 2006
				First Named Inventor	Karsten Buse
				Art Unit	N/A 1792
				Examiner Name	Not Yet Assigned—Hiteshew
Sheet	1	of	1	Attorney Docket Number	20811/0204481-US0

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
/F.H./	AA*	US-3,700,912	10-24-1972	Glass et al.	
/F.H./	AB*	US-3,932,299	01-13-1976	Phillips	
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/F.H./	BA	DE-10300080	07-22-2004	Deutsche Telekom Ag	T ⁶

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NON PATENT LITERATURE DOCUMENTS					
Examiner Initials	Cite No. ¹	Include name of the author (In CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			T ²
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Examiner Signature	/Felisa Hiteshew/	Date Considered	01/18/2008
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